

C1210C151JGGACTU

Aliases (C1210C151JGGAC7800) SMD Comm COG HV, Ceramic, 150 pF, 5%, 2,000 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1210, 1.5 mm



	General Information	
	Series	SMD Comm COG HV
	Style	SMD Chip
	Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I
	Features	Ultra-Stable, Low Loss, Class I
	RoHS	Yes
	Termination	Tin
	Marking	No
	AEC-Q200	No
	Typical Component Weight	70 mg
	Shelf Life	78 Weeks
	MSI	1

Dimensions	
Chip Size	1210
L	3.2mm +/-0.2mm
W	2.5mm +/-0.2mm
т	1.7mm +/-0.20mm
S	1.5mm MIN
В	0.5mm +/-0.25mm

Click here for the 3D model.

Packaging SpecificationsPackagingT&R, 180mm, Plastic TapePackaging Quantity2000

MSL	1		
Specifications			
Capacitance	150 pF		
Measurement Condition	1 MHz 1.0Vrms		
Tolerance	5%		
Voltage DC	2000 VDC		
Dielectric Withstanding Voltage	2,400 VDC		
Temperature Range	-55/+125°C		
Temp. Coefficient	COG		
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms		
Dissipation Factor	0.1% 1 MHz 1.0Vrms		
Aging Rate	0% Loss/Decade Hour		
Insulation Resistance	100 GOhms		

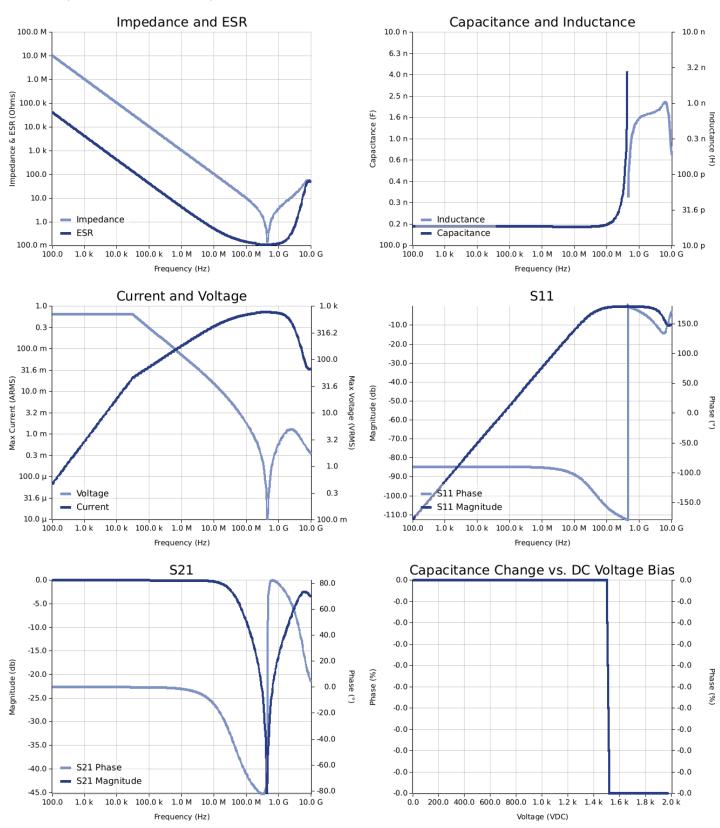
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C1210C151JGGACTU Aliases (C1210C151JGGAC7800) SMD Comm C0G HV, Ceramic, 150 pF, 5%, 2,000 VDC, C0G, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1210, 1.5 mm

Simulations

For the complete simulation environment please visit K-SIM.





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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for hipple klipple current younge vs. requericy plots is the ESR at an bient temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages and the part of the parts of the part of the
- generated at any other harmonics.
 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.